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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/752,092	01/07/2004		Masatomo Shibata	035532-0138	2332
22428	7590	07/25/2005		EXAM	INER
FOLEY AN	D LARI	ONER	BLUM, DAVID S		
SUITE 500 3000 K STRE	ET NW			ART UNIT	PAPER NUMBER
WASHINGTON DC 20007				2813	-

DATE MAILED: 07/25/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		At				
	Application No.	Applicant(s)				
Office Action Commons	10/752,092	SHIBATA, MASATOMO				
Office Action Summary	Examiner	Art Unit				
	David S. Blum	2813				
The MAILING DATE of this communication Period for Reply	appears on the cover sheet v	vith the correspondence address				
A SHORTENED STATUTORY PERIOD FOR RI THE MAILING DATE OF THIS COMMUNICATIO - Extensions of time may be available under the provisions of 37 CF after SIX (6) MONTHS from the mailing date of this communicatio - If the period for reply specified above is less than thirty (30) days, - If NO period for reply is specified above, the maximum statutory p - Failure to reply within the set or extended period for reply will, by s Any reply received by the Office later than three months after the earned patent term adjustment. See 37 CFR 1.704(b).	ON. FR 1.136(a). In no event, however, may a n. a reply within the statutory minimum of th eriod will apply and will expire SIX (6) MC statute, cause the application to become A	reply be timely filed inty (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on _						
2a) This action is FINAL . 2b) ⊠	This action is non-final.					
•—	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice und	der <i>Ex parte Quayle</i> , 1935 C.	D. 11, 453 O.G. 213.				
Disposition of Claims						
4) Claim(s) 1-16 is/are pending in the application	ation.					
4a) Of the above claim(s) is/are with	ndrawn from consideration.					
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>1-16</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction a	nd/or election requirement.					
Application Papers	·					
9) The specification is objected to by the Exa						
10)⊠ The drawing(s) filed on 18 May 2005 is/are						
Applicant may not request that any objection to						
Replacement drawing sheet(s) including the co						
11) The oath or declaration is objected to by the	ie Examiner. Note the attach	ed Office Action of form PTO-152.				
Priority under 35 U.S.C. § 119						
 12) Acknowledgment is made of a claim for for a) All b) Some * c) None of: 1. Certified copies of the priority docur 	ments have been received.	·				
2. Certified copies of the priority docur3. Copies of the certified copies of the	priority documents have bee					
application from the International Bu	*	at received				
* See the attached detailed Office action for a	a list of the certified copies no	n received.				
Attachment(s)						
1) Notice of References Cited (PTO-892)		Summary (PTO-413)				
 2) Notice of Draftsperson's Patent Drawing Review (PTO-94) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/S 	· · · · · · · · · · · · · · · · · · ·	o(s)/Mail Date Informal Patent Application (PTO-152)				
Paper No(s)/Mail Date <u>8/18/04</u> 7 01/07/200+	6) Other: _					

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This action is in response to the application filed 1/7/04.

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-16 are rejected under 35 U.S.C. 102(b) as being anticipated by Motoki (US 20020028564A1).

Motoki teaches the device of claims 1-16 as follows.

Motoki teaches an ingot or substrate with a mirror flat surface (paragraphs 0358, 0366, and 0367). Motoki does not mention that the average angles in the substrate surface are greater than its variance (claim 1), however, this is a normal statistical result, that a measurement is greater than its variance. Further, as in claim 11, mirror polishing provides this result and the surface of Motoki is mirror flat (paragraph 0367). A mirror flat finish would also describe the limitations of claim 2, where there is a flat surface, an inclination angle with a variation that is nearly constant at an arbitrary point (also in claim 4). A mirror flat finish would also describe the limitations of claim 3, where there is

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a flat surface, a normal vector of an inclination angle with a variation that is less than 180 degrees (also in claim 5).

Regarding claim 6, the substrate is a group III-V (gallium nitride) single crystal and is hetero-epitaxial (more than one type of atom) on a hetero-substrate (seed layer of GaN paragraphs 0366 and 0367). Regarding the limitation of "grown", that is a process limitation and given no patentable weight in these device claims.

Even though product-by-process claims are limited by and defined by the process, determination of Patentability is based upon the product itself. The patenability of a product does not depend on its method of production." MPEP 2113

Regarding claim 7, the group III-V (gallium nitride) single crystal is a self-standing substrate (GaN on GaN, no support substrate).

Regarding claim 8, the group III-V (gallium nitride) single crystal is a hexagonal system (both the instant application and Bensaoula teach GaN. Thus the GaN of Motoki is hexagonal as in the instant application.

Regarding claim 9, the group III-V (gallium nitride) single crystal is of a hexagonal system (as above) and the low index surface closest to the substrate is the C-surface (paragraph 0358).

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Regarding claim 10, the group III-V (gallium nitride) single crystal is of a hexagonal system (as above) and the low index surface closest to the substrate may be the Asurface, the M-surface, or the R-surface (paragraphs 0360-0369).

Regarding claim 11, the substrate is mirror finished (mirror flat (paragraph 0367) reads on mirror finished). Regarding the limitation that the surface is mirror finished, that is a process limitation and given no patentable weight. The patenability of a product does not depend on its method of production." MPEP 2113

Regarding claim 12, mirror flat reads on theta being 10 degrees or less (mirror flat reads on mirror finish. The two surfaces having a mirror finish would be within the limitations of theta.

Regarding claim 13, mirror flat reads on alpha being 1 degree or less (mirror flat reads on mirror finish. The two surfaces having a mirror finish would be within the limitations of the variance of alpha.

Regarding claim 14, mirror flat reads on theta being 10 degrees or less (mirror flat reads on mirror finish. The two surfaces having a mirror finish would be within the limitations of theta and within the limitations of the variance of alpha.

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Regarding claim 15, the low surfaces closest to the surface are c-face as above and the inclination direction in A-axis direction (figures 14-16).

Regarding claim 15, the low surfaces closest to the surface are c-face as above and the inclination direction in M-axis direction (figures 14-16).

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to David S. Blum whose telephone number is (571)-272-1687) and e-mail address is David.blum@USPTO.gov.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl Whitehead Jr., can be reached at (571)-272-1702. Our facsimile number all patent correspondence to be entered into an application is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

David S. Blum

July 21, 2005